

TSX9291, TSX9292

Datasheet - **production data**

16 MHz rail-to-rail CMOS 16 V operational amplifiers

SOT23-5 (TSX9291) DFN8 2x2 (TSX9292) MiniSO8 (TSX9292) SO8 (TSX9292)

Features

- Rail-to-rail input and output
- Wide supply voltage: 4 V 16 V
- Gain bandwidth product: 16 MHz typ at 16 V
- Low power consumption: 2.8 mA typ at 16 V
- Slew rate: 27 V/μs
- Stable when used in gain configuration
- Low input bias current: 10 pA typ
- High tolerance to ESD: 4 kV HBM
- Extended temperature range: -40° C to +125° C
- Automotive qualification

Related products

- See the TSX5 series for low power features
- See the TSX6 series for micro power features
- See the TSX92 series for unity gain stability
- See the TSV9 series for lower voltage

Applications

- **Communications**
- Process control
- Active filtering
- Test equipment

Description

The TSX9291 and TSX9292 operational amplifiers (op-amps) offer excellent AC characteristics such as 16 MHz gain bandwidth, 27 V/μs slew rate, and 0.0003 % THD+N. They are decompensated amplifiers which are stable when used with a gain higher than 2 or lower than -1. The rail-to-rail input and output capability of these devices operates on a wide supply voltage range of 4 V to 16 V. These last two features make the TSX929x series particularly welladapted for a wide range of applications such as communications, I/V amplifiers for ADCs, and active filtering applications.

Table 1. Device summary

This is information on a product in full production.

Contents

1 Package pin connections

2 Absolute maximum ratings and operating conditions

1. All voltage values, except the differential voltage are with respect to network ground terminal.

2. The differential voltage is the non-inverting input terminal with respect to the inverting input terminal.

3. Input current must be limited by a resistor in series with the inputs.

4. Short-circuits can cause excessive heating and destructive dissipation.

5. R_{th} are typical values.

6. According to JEDEC standard JESD22-A114F

7. According to JEDEC standard JESD22-A115A

8. According to ANSI/ESD STM5.3.1

Table 3. Operating conditions

3 Electrical characteristics

Table 4. Electrical characteristics at V_{CC+} = +4.5 V with V_{CC-} = 0 V, V_{icm} = V_{CC}/2, T_{amb} = 25 ° C, and **R**_L = 10 kΩ connected to V_{CC}/2 (unless otherwise specified)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
V_{io}	Input offset voltage	V_{icm} = 2 V T_{min} < T_{op} < T_{max}			4 5	mV
$\Delta V_{io}/\Delta T$	Input offset voltage drift			$\overline{2}$	10	μ V/°C
I_{ib}	Input bias current	$V_{\text{out}} = V_{\text{CC}}/2$ T_{min} < T_{op} < T_{max}		10	100 200	рA
I_{io}	Input offset current	$V_{\text{out}} = V_{\text{CC}}/2$ T_{min} < T_{op} < T_{max}		10	100 200	
R_{IN}	Input resistance			$\mathbf{1}$		$T\Omega$
C_{IN}	Input capacitance			8		pF
CMR	Common mode rejection ratio 20 log ($\Delta V_{\text{ic}}/\Delta V_{\text{io}}$)	V_{icm} = -0.1 V to 2 V, $V_{OUT} = V_{CC}/2$ T_{min} < T_{op} < T_{max}	61 59	82		dB
		V_{icm} = -0.1 V to 4.6 V, $V_{OUT} = V_{CC}/2$ T_{min} < T_{op} < T_{max}	59 57	72		
A_{vd}	Large signal voltage gain	R_L = 2 k Ω , V_{out} = 0.3 V to 4.2 V T_{min} < T_{op} < T_{max}	100 90	108		
		R_L = 10 kΩ, V _{out} = 0.2 V to 4.3 V T_{min} < T_{op} < T_{max}	100 90	112		
V_{OH}	High level output voltage	$R_1 = 2 k\Omega$ to $V_{CC}/2$ T_{min} < T_{op} < T_{max}		50	80 100	mV from V_{CC} +
		R_L = 10 kΩ to $V_{CC}/2$ T_{min} < T_{op} < T_{max}		10	16 20	
V_{OL}	Low level output voltage	$R_1 = 2 k\Omega$ to $V_{CC}/2$ T_{min} < T_{op} < T_{max}		42	80 100	mV
		R_L = 10 kΩ to V _{CC} /2 T_{min} < T_{op} < T_{max}		9	16 20	
I_{out}	I _{sink}	$V_{\text{out}} = 4.5 V$ T_{min} < T_{op} < T_{max}	16 13	21		mA
	Isource	$V_{\text{out}} = 0 V$ T_{min} < T_{op} < T_{max}	16 13	21		
$I_{\rm CC}$	Supply current (per amplifier)	No load, $V_{\text{out}} = V_{\text{CC}}/2$ T_{min} < T_{op} < T_{max}		2.9	3.4 3.5	
GBP	Gain bandwidth product	R_L = 10 k Ω , C_L = 20 pF, G = 20 dB		15.6		MHz
F_U	Unity gain frequency	$R_1 = 10 k\Omega$, $C_1 = 20 pF$		14.2		
Gain	Minimum gain for stability	Phase margin = 60 °, R_f = 10 k Ω $R_1 = 10 k\Omega$, $C_1 = 20 pF$		-1 $+2$		

Figure 2. Supply current vs. supply voltage

Figure 4. Distribution of input offset voltage at Figure 5. Input offset voltage vs. temperature at V_{CC} = 16 V V_{CC} = 16 V

 Figure 6. Distribution of input offset voltage drift over temperature

Figure 7. Input offset voltage vs. common mode voltage at $V_{CC} = 4 V$

 $-3.0 = 0.0$

Vcc=16V

-2.4 -1.8 -1.2 -0.6 0.0 0.6 1.2 1.8

Input offset voltage (mV)

Input offset voltage (mV)

voltage at V_{CC} = 16 V

0.0 1.5 3.0 4.5 6.0 7.5 9.0 10.5 12.0 13.5 15.0 **Common mode voltage(V)**

T=-40°C

 $T=125^{\circ}C$

 V_{CC} = 16 V

 $T=25^\circ C$

Figure 14. Bode diagram vs. temperature for

Figure 15. Bode diagram vs. temperature for

 Figure 16. Bode diagram vs. temperature for V_{CC} = 16 V

Figure 18. Bode diagram at V_{CC} = 16 V with high

common mode voltage

Figure 17. Bode diagram at V_{CC} = 16 V with low **common mode voltage**

Figure 19. Bode diagram at V_{CC} = 16 V and $R_1 = 10 k\Omega C_1 = 47 pF$

 Figure 22. Small signal overshoot vs capacitive load without feedback capacitor Cf

 Figure 24. Small step response with feedback capacitor

Figure 23. Small step response with G = +2

Figure 25. Large step response

 Figure 28. Output impedance vs frequency in close loop configuration

Figure 30. 0.1 to 10 Hz noise with 16 V supply voltage

Figure 27. Peaking close loop with different RI

Figure 29. Noise vs. frequency with 16 V supply voltage

Figure 31. THD+N vs. frequency at V_{CC} = 16 V

Figure 32. THD+N vs. output voltage at V_{CC} = 16 V

Figure 33. Power supply rejection ratio (PSRR) vs. frequency

Figure 34. Crosstalk vs. frequency between operators on TSX9292 at V_{CC} = 16 V

4 Application information

4.1 Operating voltages

The TSX929x series of operation amplifiers can operate from 4 V to 16 V. Parameters are fully specified at 4.5 V, 10 V, and 16 V power supplies. However, parameters are very stable in the full V_{CC} range. Additionally, the main specifications are guaranteed in the extended temperature range of -40 to +125 °C.

4.2 Rail-to-rail input

The TSX9291 and TSX9292 are designed with two complementary PMOS and NMOS input differential pairs. The devices have a rail-to-rail input and the input common mode range is extended from (V_{CC}) - 0.1 V to (V_{CC+}) + 0.1 V. However, the performance of these devices is clearly optimized for the PMOS differential pairs (which means from (V_{CC}) - 0.1 V to $(V_{CC+}) - 2 V$).

Beyond (V_{CC+}) - 2 V, the operational amplifiers are still functional but with downgraded performances (see *[Figure](#page-12-0) 19*). Performances are still suitable for a large number of applications requiring the rail-to-rail input feature.

TSX9291 and TSX9292 are designed to prevent phase reversal.

4.3 Input pin voltage range

The TSX929x series has internal ESD diode protection on the inputs. These diodes are connected between the input and each supply rail to protect MOSFETs inputs from electrostatic discharges.

Thus, if the input pin voltage exceeds the power supply by 0.5 V, the ESD diodes become conductive and excessive current could flow through them. To prevent any permanent damage, this current must be limited to 10 mA. This can be done by adding a resistor in series with the input pin (*[Figure](#page-16-4) 35*). The resistor value has to be calculated for a 10 mA current limitation on the input pins.

Figure 35. Limiting input current with a series resistor

4.4 Stability for gain = -1

TSX9291 and TSX9292 can be used in gain = -1 configuration (see *[Figure](#page-17-1) 36*). However some precautions must be taken regarding the setting of the Rg and Rf resistors. Effectively, the input capacitance of the TSX929x series creates a pole with Rf and Rg. In high frequency, this pole decreases the phase margin and also causes gain peaking. This effect has a direct impact on the stability.

[Figure](#page-17-2) 37 shows the peaking, depending on the values of the gain and feedback resistances.

Figure 36. Configuration for gain = -1

Figure 37. Close loop gain vs. frequency

Whenever possible, it is best to choose smaller feedback resistors. It is recommended to use 1 kΩ gain and feedback resistance (Rf and Rg) when gain = -1 is necessary. In the application, if a large value of Rf and Rg has to be used, a feedback capacitance can be added in parallel with Rf, to reduce or eliminate the gain peaking. Additionally, Cf helps to compensate the input capacitance and to increase stability.

[Figure](#page-18-1) 38 shows how Cf reduces the gain peaking.

4.5 Capacitive load

Driving a large capacitive load can cause stability issues. Increasing the load capacitance produces gain peaking in the frequency response, with overshooting and ringing in the step response. It is usually considered that with a gain peaking higher than 2.3 dB the op-amp might become unstable. Generally, the unity gain configuration is the worst configuration for stability and the ability to drive large capacitive loads. *[Figure](#page-19-0) 39* shows the serial resistor (Riso) that must be added to the output, to make the system stable. *[Figure](#page-19-1) 40* shows the test configuration for Riso.

Figure 40. Test configuration for Riso

4.6 High side current sensing

TSX9291 and TSX9292 rail to rail input devices can be used to measure a small differential voltage on a high side shunt resistor and translate it into a ground referenced output voltage. The gain is fixed by external resistance.

V_{OUT} can be expressed as shown in *[Equation 1](#page-20-1)*.

Equation 1

$$
V_{out} \,=\, R_{shunt} \times \,I\Big(1-\frac{R_{g2}}{R_{g2}+R_{f2}}\Big)\Big(1+\frac{R_{f1}}{R_{g1}}\Big)+I_p\Big(\frac{R_{g2}R_{f2}}{R_{g2}+R_{f2}}\Big) \times \Big(1+\frac{R_{f1}}{R_{g1}}\Big)-I_nxR_{f1}-V_{io}\Big(1+\frac{R_{f1}}{R_{g1}}\Big)
$$

Assuming that R_{f2} = R_{f1} = R_f and R_{g2} = R_{g1} = R_g , *[Equation 1](#page-20-1)* can be simplified as *[Equation 2](#page-20-2)*.

Equation 2

$$
V_{out} = R_{shunt} \times I\left(\frac{R_f}{R_g}\right) - V_{io}\left(1 + \frac{R_f}{R_g}\right) + R_f \times I_{io}
$$

With the TSX929x series, the high side current measurement must be made by respecting the common mode voltage of the amplifier: (V_{CC}) - 0.1V to (V_{CC+}) + 0.1V. If the application requires a higher common voltage, please refer to the TSC high side current sensing family.

4.7 High speed photodiode

The TSX929x series is an excellent choice for current to voltage (I-V) conversions. Due to the CMOS technology, the input bias currents are extremely low. Moreover, the low noise and high unity-gain bandwidth of TSX9291 TSX9292 make them particularly suitable for high-speed photodiode preamplifier applications.

The photodiode is considered as a capacitive current source. The input capacitance, C_{IN} , includes the parasitic input common mode capacitance, C_{CM} (3pF), and the input differential mode capacitance, C_{DIFF} (8pF). C_{IN} acts in parallel with the intrinsic capacitance of the photodiode, C_D . At higher frequencies, the capacitors affect the circuit response. The output capacitance of a current sensor has a strong effect on the stability of the op-amp feedback loop.

 C_F stabilizes the gain and limits the transimpedance bandwidth. To ensure good stability and to obtain good noise performance, C_F can be set as shown in *[Equation 3](#page-21-1)*.

Equation 3

$$
C_F > \sqrt{\frac{C_{IN} + C_D}{2 - \pi \cdot R_F \cdot F_{GBP}}} - C_{SMR}
$$

where,

- $C_{IN} = C_{CM} + C_{DIFF} = 11 pF$
- C_{DIFF} is the differential input capacitance: 8 pF typical
- C_{CM} is the Common mode input capacitance: 3 pF typical
- C_D is the intrinsic capacitance of the photodiode
- C_{SMR} is the parasitic capacitance of the surface mount R_{F} resistor: 0.2 pF typical
- F_{GBP} is the gain bandwidth product: 10 MHz at 16 V

RF fixes the gain as shown in *[Equation 4](#page-21-2)*.

Equation 4

 $V_{OUT} = R_F \times I_D$

Figure 42. High speed photodiode

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5 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK® is an ST trademark.

5.1 SOT23-5 package mechanical data

Table 7. SOT23-5 package mechanical data

5.2 DFN8 2x2 package information

Figure 44. DFN8 2x2 package mechanical drawing

Table 8. DFN8 2x2 package mechanical data

5.3 MiniSO8 package information

Table 9. **MiniSO8 package mechanical data**

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5.4 SO8 package information

Figure 46. SO8 package mechanical drawing

Table 10. SO8 package mechanical data

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6 Ordering information

Table 11. Order codes

1. Qualified and characterized according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 & Q 002 or equivalent.

7 Revision history

Table 12. Document revision history

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